

High-Voltage Schottky Rectifier

FEATURES

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation

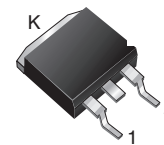


RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

TO-252-2L



MBRB1090
MBRB10100

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	10 A
V_{RRM}	90 V, 100 V
I_{FSM}	150 A
V_F	0.65 V
T_J max.	150 °C

MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	MBR1090	MBR10100	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	90	100	V
Working peak reverse voltage	V_{RWM}	90	100	V
Maximum DC blocking voltage	V_{DC}	90	100	V
Maximum average forward rectified current at $T_C = 133$ °C	$I_{F(AV)}$	10		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	150		A
Peak repetitive reverse current at $t_p = 2$ μ s, 1 kHz	I_{RRM}	0.5		A
Voltage rate of change (rated V_R)	dV/dt	10 000		V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	- 65 to + 150		°C
Isolation voltage (ITO-220AC only) From terminal to heatsink $t = 1$ min	V_{AC}	1500		V

ELECTRICAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	$I_F = 10\text{ A}$	$T_C = 25\text{ }^\circ\text{C}$	V_F	0.80	V
	$I_F = 10\text{ A}$	$T_C = 125\text{ }^\circ\text{C}$		0.65	
	$I_F = 20\text{ A}$	$T_C = 125\text{ }^\circ\text{C}$		0.75	
Maximum reverse current at working peak reverse voltage ⁽²⁾			I_R	100	μA
				6.0	mA

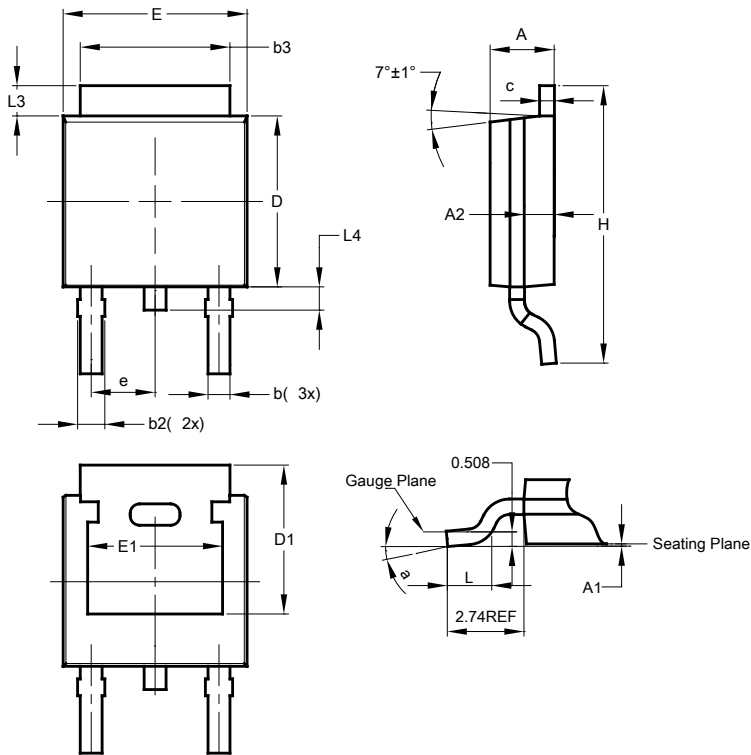
Notes:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width $\leq 40\text{ ms}$

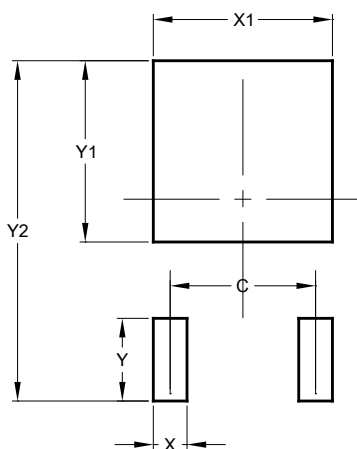
THERMAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance	$R_{\theta JA}$	60	-	60	$^\circ\text{C/W}$
	$R_{\theta JC}$	2.0	3.5	2.0	

Package Outline Dimensions



TO252 (DPAK)			
Dim	Min	Max	Typ
A	2.19	2.39	2.29
A1	0.00	0.13	0.08
A2	0.97	1.17	1.07
b	0.64	0.88	0.783
b2	0.76	1.14	0.95
b3	5.21	5.46	5.33
c	0.45	0.58	0.531
D	6.00	6.20	6.10
D1	5.21	-	-
e	-	-	2.286
E	6.45	6.70	6.58
E1	4.32	-	-
H	9.40	10.41	9.91
L	1.40	1.78	1.59
L3	0.88	1.27	1.08
L4	0.64	1.02	0.83
a	0°	10°	-
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
C	4.572
X	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700

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